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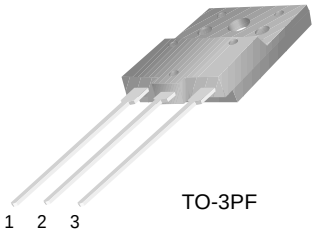
FFAF10U20DN

Features

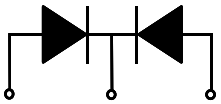
- Ultrafast with soft recovery
- Low forward voltage

Applications

- Power switching circuits
- Output rectifiers
- Freewheeling diodes
- Switching mode power supply



TO-3PF



1. Anode 2.Cathode 3. Anode

ULTRA FAST RECOVERY POWER RECTIFIER

Absolute Maximum Ratings (per diode) T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ T_C = 100°C	10	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	100	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	4.0	°C/W

Electrical Characteristics (per diode) T_C=25 °C unless otherwise noted

Symbol	Parameter		Min.	Typ.	Max.	Units
V_{FM} *	Maximum Instantaneous Forward Voltage					V
	I_F = 10A	T_C = 25 °C	-	-	1.2	
	I_F = 10A	T_C = 100 °C	-	-	1.0	
I_{RM} *	Maximum Instantaneous Reverse Current					µA
	@ rated V_R	T_C = 25 °C	-	-	10	
		T_C = 100 °C	-	-	100	
t_{rr}	Maximum Reverse Recovery Time		-	-	35	ns
I_{rr}	Maximum Reverse Recovery Current		-	-	2.5	A
Q_{rr}	Maximum Reverse Recovery Charge (I_F =10A, di/dt = 200A/µs)		-	-	45	nC
W_{AVL}	Avalanche Energy		0.5	-	-	mJ

* Pulse Test: Pulse Width=300µs, Duty Cycle=2%

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Typical Characteristics

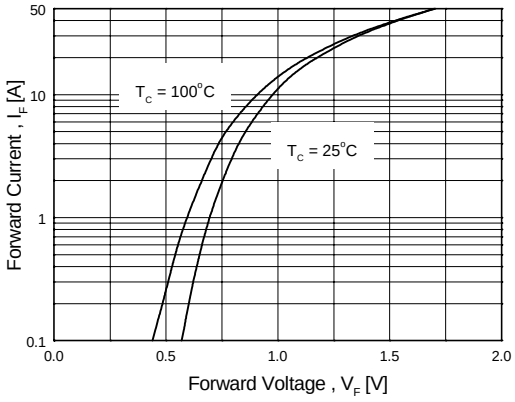


Figure 1. Typical Forward Voltage Drop vs. Forward Current

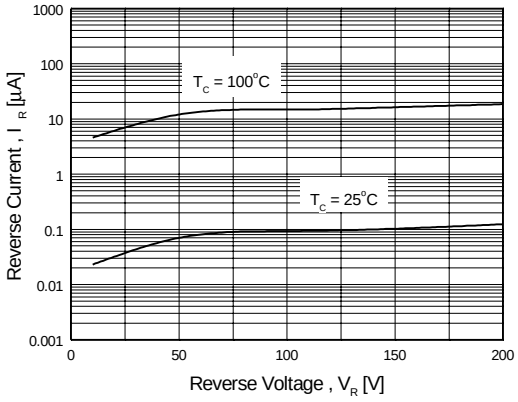


Figure 2. Typical Reverse Current vs. Reverse Voltage

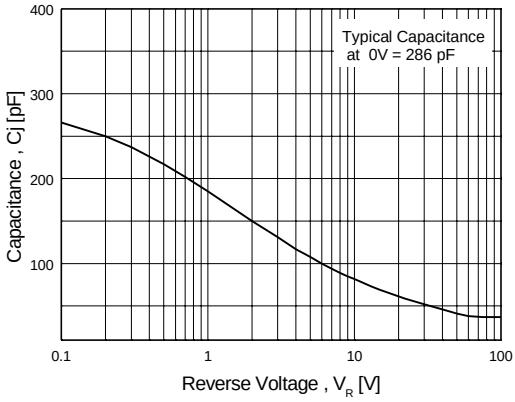


Figure 3. Typical Junction Capacitance

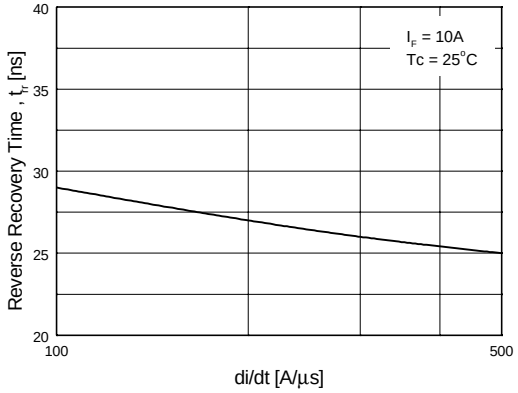


Figure 4. Typical Reverse Recovery Time vs. di/dt

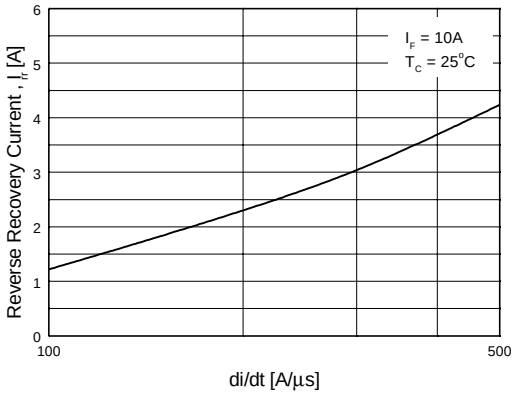


Figure 5. Typical Reverse Recovery Current vs. di/dt

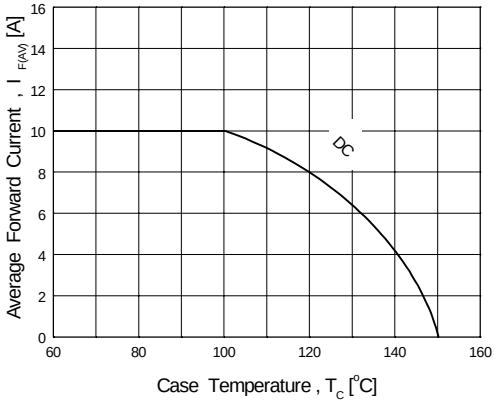
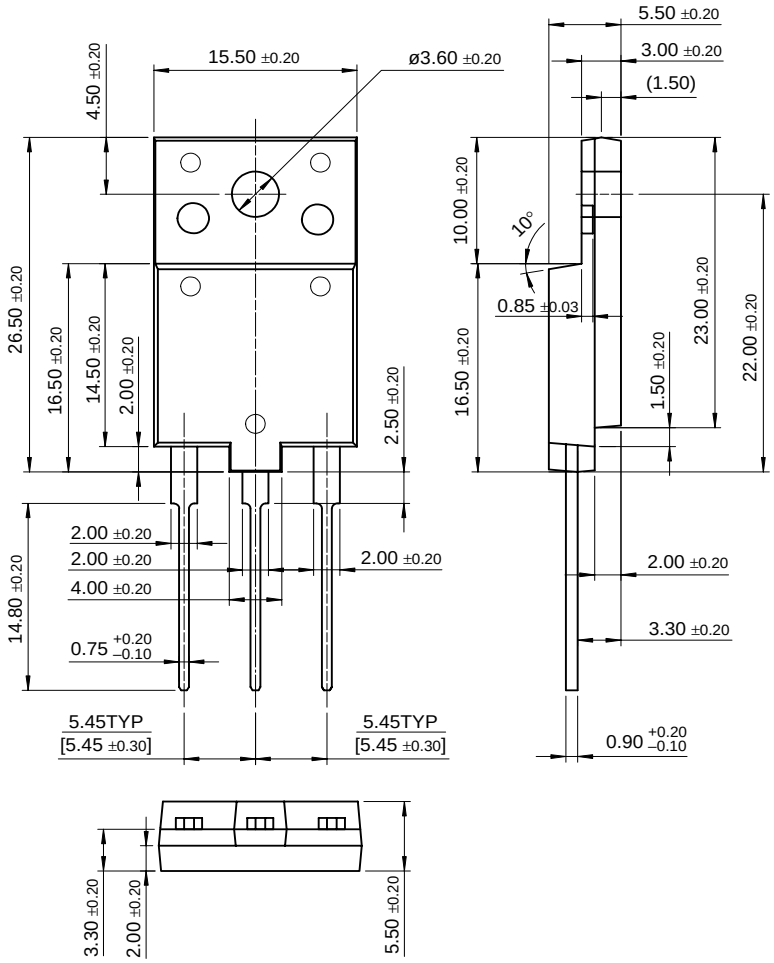


Figure 6. Forward Current Derating Curve

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Package Dimensions

TO-3PF



Dimensions in Millimeters

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